## NSN 5961-00-175-9206

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#### **Inclosure Material:**

Metal and ceramic

#### **Overall Length:**

0.270 inches

#### **Overall Height:**

0.320 inches

#### **Overall Diameter:**

0.360 inches

#### **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Emitter

#### **Mounting Method:**

Threaded stud

### Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

90.0 breakdown voltage, collector-to-base, emitter open

#### **Current Rating Per Characteristic:**

3.30 amperes all primaries

#### **Power Rating Per Characteristic:**

70.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 pin

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

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